



AP3190T

PRIMARY SIDE REGULATED SWITCHING MODE POWER SUPPLY CONTROLLER

Description

The AP3190T is a high-performance offline PSR AC/DC power supply controller. It is specially designed for the application that require the higher efficiency at light load and cost effectiveness.

Using the multi-mode control scheme, the AP3190T can also achieve high conversion efficiency with full load conditions. At heavy load and low line, the AP3190T will operate in QR mode to achieve high performance. When the load decreasing, it will enter into fixed switching frequency operating mode. To optimize product performance, the fixed frequency is different in high line (60kHz) and low line (80kHz).

The AP3190T is traditional PSR CVCC controller. The controller samples the V_{CS} peak current and the demagnetization pulse to regulation the output current. The current and output power setting can be adjusted externally by the sense resistor at CS pin.

The AP3190T provides comprehensive protections without additional circuitry. It contains V_{CC} overvoltage protection, output overvoltage protection, output short circuit protection, etc.

The AP3190T has adjustable OTP by external NTC resistor. It consumes less than 65mW input power at no load condition with high line voltage.

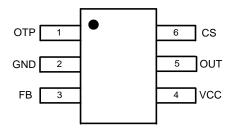
The AP3190T is packaged in SOT26 (Type SM).

Features

- Primary Side Control for Eliminating Opto-Coupler
- 65mW No-Load Input Power
- Ultra-Low Under Voltage Protection
- Adjustable Over Temperature Protection
- Multiple QR/AM Mode to Improve Audio Noise and Efficiency
- QR for Higher Efficiency and Better EMI
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Pin Assignments

(Top View)



SOT26 (Type SM)

Applications

- Power tools
- Set-top box power supplies
- Network adaptors

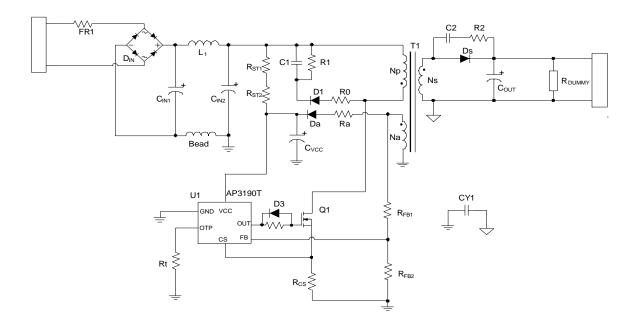
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Typical Applications Circuit

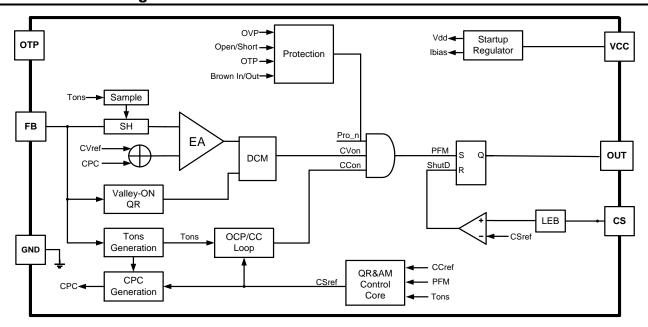


Pin Descriptions

Pin Number	Pin Name	Function	
1	ОТР	Adjustable over temperature protection by external NTC resistor	
2	GND	The ground of the controller	
3	FB	The CV and CC regulation are realized based on the voltage sampling of this pin.	
4	VCC	The VCC pin supplies the power for the IC.	
5	OUT	Output pin to drive external MOSFET	
6	CS	The CS is the current sense pin of the IC. The IC will turn off the power MOSFET according to the voltage on the CS pin.	



Functional Block Diagram



Absolute Maximum Ratings (Note 4)

Symbol	Parameter	Rating	Unit
Vcc	Supply Voltage	-0.3 to 33	V
Vouт	Output Voltage	-0.3 to 15.7	V
V _{CS}	Input Voltage	-0.3 to 7.9	V
V _{FB}	FB Input Voltage	-0.3 to 7.9	V
TJ	Operating Junction Temperature	-40 to +150	°C
Тѕтс	Storage Temperature	-65 to +150	°C
TLEAD	Lead Temperature (Soldering, 10s)	+300	°C
θ _{JC}	Thermal Resistance (Junction to Case) (Note 5)	76	°C/W
θја	Thermal Resistance (Junction to Ambient) (Note 5)	200	°C/W
_	ESD (Human Body Model)	4000	V
_	ESD (Charge Device Model)	1000	V

Notes:

- 4. Stresses greater than those listed under "Absolute Maximum Ratings" can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods can affect device reliability.
- 5. Test condition: Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch pad layout.

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Unit
Vcc	Supply Voltage (Note 6)	0	28	V
T _A	Ambient Temperature	-40	+85	°C

Note: 6. The VCC is 85% of the recommended maximum value in the aging condition.



$\textbf{Electrical Characteristics} \ (@V_{CC} = 15V, \ T_{A} = +25^{\circ}C, \ unless \ otherwise \ specified.)$

Symbol	Parameter	Condition	Min	Тур	Max	Unit	
STARTUP AND UVLO SE	ECTION		<u> </u>		l		
V _{TH_ST}	Startup Threshold	_	13	15	17	V	
Vopr(MIN)	Minimum Operating Voltage	_	5.8	6.15	6.5	V	
CURRENT SECTION		l		I			
Ist	Startup Current	Vcc = V _{TH_ST} -1V before Startup	0.009	0.5	1.1	μΑ	
Icc_opr	Operating Current	Static Current	396	450	502	μΑ	
CURRENT SENSE SECT	ION						
Vcs_H	Maximum Current Sense Threshold Voltage at CV Mode	(Note 7)	968	1100	1232	mV	
V _{CS_M}	Medium Current Sense Threshold Voltage at CV Mode at Low Line	(Note 7)	545	620	695	mV	
VCS_M	Medium Current Sense Threshold Voltage at CV Mode at High Line	(Note 7)	677	770	863	mV	
Vcs_L	Minimum Current Sense Threshold Voltage at CV Mode	(Note 7)	281	320	358	mV	
t _{LEB}	Leading Edge Blanking	_	198	275	352	ns	
CONSTANT VOLTAGE S	ECTION						
V _{FB}	Feedback Threshold Voltage	Test @ 90% of I _{OUT}	2.7	2.74	2.784	V	
RCABLE	Cable Compensation Ratio	_	_	2	_	%	
CONSTANT CURRENT S	ECTION						
V _{REF_CC}	Constant Current Reference	(Note 8)	0.427	0.45	0.473	V	
RLINE_IC	Fixed Line Compensation Resistor	_	158	173	189	Ω	
DRIVE SECTION (OUT P	in)						
ISOURCE_L	Minimum Drive Current	_	7.9	10.8	13.8	mA	
Isource_h	Maximum Drive Current	_	21.0	27.7	34.3	mA	
Rds_on	Sink Resistance	_	3.4	3.75	4.1	Ω	
MAXIMUM OPERATING I	FREQUENCY						
F	Maximum Frequency at Low Line	Fsw During AM2	72	80	88	kHz	
Fsw_max	Maximum Frequency at High Line	Fsw During AM2	54	60	66	kHz	
SAMPLE TIME							
tsample_h	0 1 7	At Heavy Load (Note 7)	_	67.0	_	0/	
tsample_L	Sample Time at tons	At Light Load (Note 7)	_	51.0	_	- %	
DYNAMIC SECTION							
toff_max	Maximum Off Time	_	3.3	3.5	3.7	ms	
•	•	•	•				

Notes:

^{7.} Guaranteed by design and characterization.

^{8.} V_{REF_CC} is the equivalent of output current (w/o contacting resistor introduced by testing).



Electrical Characteristics (@Vcc = 15V, TA = +25°C, unless otherwise specified. continued)

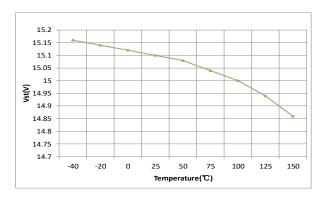
Symbol	Parameter	Condition	Min	Тур	Max	Unit
PROTECTION FUNCTION	PROTECTION FUNCTION SECTION					
Vcc_ovp	Over Voltage Protection at VCC Pin	_	29	30	31	V
Vfb_ovp	Over Voltage Protection	(Note 7)	_	3.5	_	V
V _{FB_SCP}	Short Circuit Protection	(Note 7)	0.58	0.6	0.62	V
tscp	Delay Time for SCP Protection	(Note 7)	44.5	46	47.5	ms
VFBNeg_H	Brown in Point	(Note 7)	_	-45	_	mV
INTERNAL TOTP	Shutdown Temperature	(Note 7)	_	+150	_	°C
INTERNAL THYS	Temperature Hysteresis	(Note 7)	_	+40	_	°C
Vотр	External OTP Shutdown Threshold	_	0.48	0.5	0.52	V
VOTP_REC	External OTP Recovery Threshold	_	0.72	0.75	0.78	V
Іотр	External OTP Shutdown Current	_	91.5	100	110	μΑ

Note: 7. Guaranteed by design and characterization.

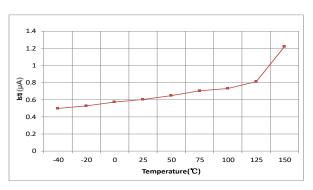


Performance Characteristics

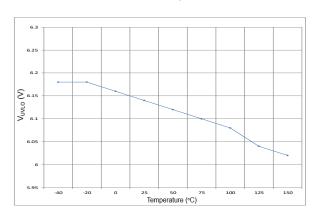
Startup Voltage vs. Temperature



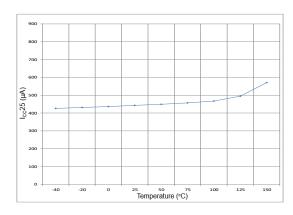
Start-Up Current vs. Ambient Temperature



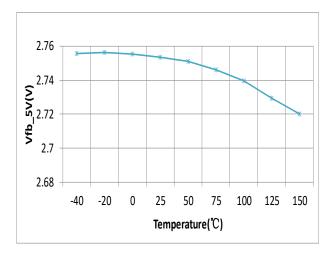
UVLO vs. Temperature



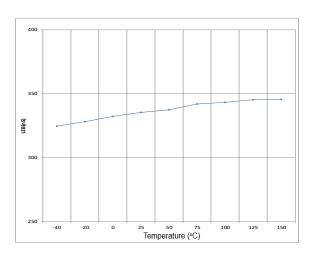
Operating Current vs. Ambient Temperature



Feedback Voltage vs. Ambient Temperature



LEB vs. Ambient Temperature





Operation Description

Constant Voltage Operation

The AP3190T captures the auxiliary winding feedback voltage at FB pin and operates in constant-voltage (CV) mode to regulate the output voltage. Assuming the secondary winding is master, the auxiliary winding is slave during D_s's on-time. The auxiliary voltage is given by:

$$V_{AUX} = \frac{N_{AUX}}{N_{c}} \cdot (V_{O} + V_{d}) \cdot \cdot \cdot \cdot \cdot \cdot \cdot \cdot (1)$$

Where VD is Ds forward drop voltage, NAUX is the turns of auxiliary winding, and Ns is the turns of secondary winding.

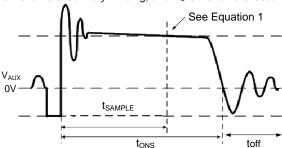


Figure 1. Auxiliary Voltage Waveform

The output voltage is different from the secondary voltage in a diode forward drop voltage VD which depends on the current. If the secondary voltage is always detected at a constant secondary current, the difference between the output voltage and the secondary voltage will be a fixed V_D. The voltage detection point is at the tsample of the Ds's on-time. The voltage detection point is changed with the different primary peak current. The CV loop control function of the AP3190T then generates a Ds's off-time to regulate the output voltage.

Constant Current Operation

The AP3190T is designed to work in constant current (CC) mode. Figure 2 shows the secondary current waveforms.

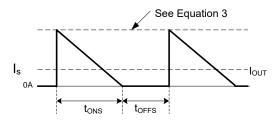


Figure 2. Secondary Current Waveform

In CC operation, the CC loop control function of the AP3190T will keep a fixed produce of the Vcs and the proportion between the Ds's on-time tons and its off-time toffs. This fixed produce is:

$$V_{ref_CC} = V_{CS} \cdot \frac{t_{ONS}}{t_{ONS} + t_{OFFS}} \cdot \dots$$
 (2)

The relation between the output constant-current and secondary peak current IPKS is given by:

$$I_{OUT} = \frac{1}{2} \times I_{PKS} \times \frac{t_{ONS}}{t_{ONS} + t_{OFFS}} \cdot \dots$$
 (3)

At the instant of Ds turn-on, the primary current transfers to the secondary at an amplitude of:

$$I_{PKS} = \frac{N_P}{N_c} \cdot I_{PK} \cdot \dots$$
 (4)

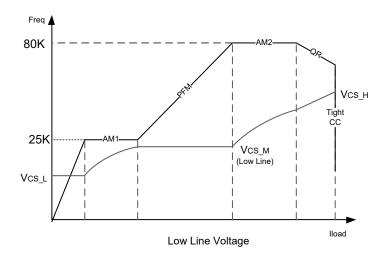
Thus the output constant current is given by:

$$I_{OUT} = \frac{1}{2} \cdot \frac{N_P}{N_S} \cdot \frac{1}{R_{CS}} \cdot V_{ref_CC} \cdot \dots$$
 (5)



Multi-Mode Operation

In CV control, the controller changes the mode of operation according to load condition. The switching frequency curve in Figure 3 shows operation modes. Proprietary CV control can achieve high precision CV control meeting most requirements.



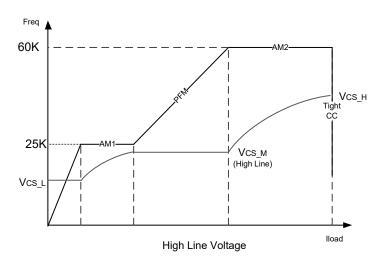


Figure 3. Multi-Mode Operation Diagram

QR Mode

At low line and heavy load, if the toff = 0, the AP3190T will operates in QR mode. QR is the abbreviation of Quasi-Resonant which is regarded as a soft switching technology. It means that the power MOSFET always turns on at the valley of the Drain-to-Source voltage (VDS). Compared to traditional hard switching, QR switching-on can reduce the switching power loss of MOSFET and achieve good EMI behavior without additional BOM cost. The VDS valley is detected by FB pin.

Leading Edge Blanking

When the power switch is turned on, a turn-on spike will occur on the sense-resistor. To avoid false-termination of the switching pulse, a 275ns leading-edge blanking (from power BJT or MOSFET on) is built in. During this blanking period, the current sense comparator is disabled and the gate driver can't be switched off.



Valley Turn-on

When the off time (toff) is lower than t_{VAL-ON}, the AP3190T power system can work with valley turn-on. It can reduce BJT or MOSFET switching on power losses which is result from the equivalent output capacitance to achieve highest overall efficiency. At the same time, because of valley turn-on the switching frequency has the random jitter feature, which will be benefit for conductive EMI performance. And valley turn-on can also reduce the power switch turn-on spike current and then achieve a better radiated EMI performance.

Adjustable Line Compensation

Since there is a delay time from the CS pin voltage reaching the given V_{CS} reference to the power MOSFET turning off, the real primary peak current value always has a gap with the ideal value. The gap value changes with different input line voltage, which is caused by different current rising slope, results in different system constant current value.

In order to eliminate the constant current deviation due to line voltage, the adjustable line compensation is introduced to the AP3190T design. The negative voltage of FB pin which is linear to the line voltage is added up to V_{CS} reference by a certain proportion and creates an adjustable compensation voltage to clear up the primary current gap, so that the excellent line regulation of output current will be achieved.

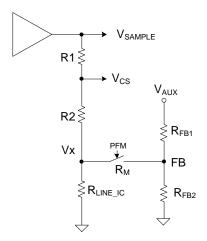


Figure 4. Adjustable Line Compensation Circuit

$$\Delta V_{CS} = -\frac{R_1}{R_1 + R_2} \cdot \frac{N_{AUX}}{N_P} \cdot \frac{R_{LINE_IC}}{R_{LC} + R_M + R_{EE1}} \cdot V_{LINE} \quad \dots \tag{6}$$

Where

 $R1=48k\Omega,\,R2=288k\Omega,\,R_M=13\Omega$

So, the AP3190T can change the line compensation capability by adjusting the upper resistor at FB pin (R_{FB1}). Higher resistance means lower line compensation capability.



Protection

The AP3190T has various built-in single-point fault protection features: For FB over voltage protection, VCC over voltage protection, and current sense open, the AP3190P will shut down if it detects fault for continuous 4 pulse. Output short circuit protection, current sense resistor short protection and over temperature protection will be description in detail below. The fault conditions to trigger these protections are different and all the protection modes to enter after the protections are triggered are auto-recovery.

Short Circuit Protection (SCP)

Short Circuit Protection (SCP) detection principle is similar to the normal output voltage feedback detection by sensing FB pin voltage. When the detected FB pin voltage is below VFB(SCP) for a duration of about tscP, the SCP is triggered. Then the AP3190T enters hiccup mode that the IC immediately shuts down and then restarts, so that the VCC voltage changes between VTH_ST and UVLO threshold until VFB(SCP) condition is removed.

As to the normal system startup, the time duration of FB pin voltage below VFB(SCP) should be less than TSCP to avoid entering SCP mode. But for the output short condition or the output voltage below a certain level, the SCP mode should happen.

Brown In/Brown Out Protection

The AP3190T detects the bus voltage at each switching cycle through the minus voltage on FB pin during t_{ONP} period. When the VCC reaches v_{TH_ST} after power on, the AP3190T will output one switching pulse to check if the minus voltage on FB pin is lower than v_{TRNeg_H} . If yes, the system will start up normally. Otherwise, the AP3190T will stop outputting following pulses until the VCC drops below $v_{OPR(MIN)}$, and the system will repeat the above-described process.

The brown in protection only works at IC start up.

Once the IC start up normally, the AP3190T will change the protection reference from brown in (V_{FBNeg_H}) to brown out (V_{FBNeg_H}/3). Throughout the entire system operation process, the AP3190T detects the minus voltage on FB pin cycle by cycle. If the detected minus voltage on FB pin is higher than V_{FBNeg_H}/3 (-15mV) for 4 consecutive switching cycles, the AP3190T will shut down and enter auto recovery mode.

$$V_{\text{FBNeg}_H} = -(\frac{N_{\text{AUX}}}{N_{P}} \cdot V_{\text{BUS}} \cdot \frac{R_{\text{LINE}_IC}}{R_{\text{LINE}_IC} + R_{\text{FB}1}})$$

CS Short Protection

The CS short protection reference (300mV) is a divider of Vcs_H, which is defined in datasheet.

The AP3190T detects the Vcs voltage $6.3\mu s$ after tonP beginning, if the voltage is lower than 300mV, the IC will enter CS short protection. This protection only works at IC start up.

$$V_{\rm CS} \ = \ I_{\rm PK} \ \cdot \ R_{\rm CS} \ = \ \frac{V_{\rm RIS}}{L_{\scriptscriptstyle D}} \ \cdot \ T_{\rm ONP} \ \cdot \ R_{\rm CS}$$

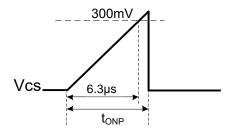


Figure 5. CS Short

Improper transformer design will lead to CS short protection & Brown in protection easily trigger. So, if system design is proper, these two protections will not affect system's normal work.



Over Temperature Protection (OTP)

External OTP

The AP3190T provides external over temperature protection (OTP) by connecting a Negative-Temperature-Coefficient (NTC) resistor from OTP pin to GND. Internally, a 100µA current source is injected to the OTP pin, which generates a voltage proportional to the NTC resistance. At high ambient temperature, the NTC resistance becomes low, which results in a low voltage at the OTP pin. If the OTP pin voltage drops below an internally set threshold, then the OTP is triggered, and the AP3190T shuts down.

In the AP3190T, the external OTP has a built-in hysteresis by having two thresholds. The device will be shut down when the OTP pin voltage is less than 0.5V and will be recovered when the OTP pin voltage is higher than 0.75V.

During start-up, the OTP function is disabled.

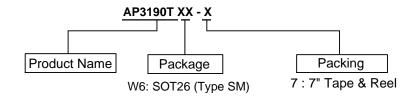
Internal OTP

If the IC junction temperature exceeds the threshold of +150°C, the AP3190T shuts down immediately and enters the hold mode. If the junction temperature decreases to hysteresis temperature of +110°C, the AP3190T can recover to normal operation. If not, the power system keeps the hold mode.

AP3190T Document number: DS45729 Rev. 4 - 2



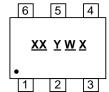
Ordering Information



Orderable Part Number	Package	Marking ID	Packing	
Orderable Part Number	Package	Warking ID	Qty.	Carrier
AP3190TW6-7	SOT26 (Type SM)	BT	3000	Tape & Reel

Marking Information

(Top View)



XX: Identification Code

Y : Year 0 to 9

W : Week : A to Z : 1 to 26 Week; a to z : 27 to 52 Week; z Represents 52 and 53 Week

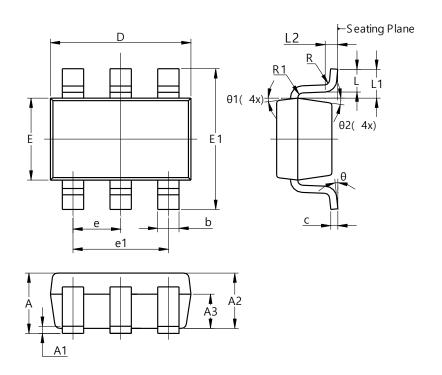
X: Internal Code



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT26 (Type SM)

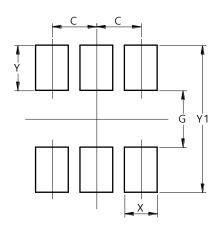


SOT26 (Type SM)					
Dim	Min	Max	Тур		
Α	-	1.45	1		
A1	0.00	0.15	1		
A2	0.90	1.30	1.10		
A3	0.60	0.70	0.65		
b	0.39	0.49	1		
С	0.12	0.19	1		
D	2.85	3.05	2.95		
Е	1.55	1.75	1.65		
E1	2.60	3.00	2.80		
е	0.85	1.05	0.95		
e1	1.80	2.00	1.90		
١	0.35	0.60	0.45		
L1		0.59RI	ΞF		
L2		0.25BS	SC		
R	0.05		1		
R1	0.05	0.20			
θ	0°	8°			
θ1	8°	12°	10°		
θ2	8°	12°	10°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT26 (Type SM)



Dimensions	Value (in mm)
С	0.950
G	1.250
X	0.700
Υ	0.975
Y1	3.200

Mechanical Data

- Moisture Sensitivity: Level 3 per JESD22-A113
- Terminals: Finish Matte Tin Plated Leads, Solderable per JESD22-B102 @3
- Weight: 0.018 grams (Approximate)



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